

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

Vishay/Siliconix SI4354DY-T1-E3

For any questions, you can email us directly: sales@integrated-circuit.com





Si4354DY

Vishay Siliconix

N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	
30	0.0165 at V _{GS} = 10 V	9.5	
	0.0185 at V _{GS} = 4.5 V	9.0	

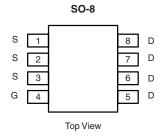
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Gen II Power MOSFET
- 100 % R_g Tested

RoHS COMPLIANT HALOGEN FREE Available

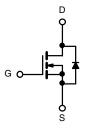
APPLICATIONS

- High-Side DC/DC Conversion
 - Notebook
 - Server



Ordering Information: Si4354DY-T1-E3 (Lead (Pb)-free)

Si4354DY-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	1 A = 25 C, unles				
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V_{GS}	± 12	v	
Continuous Dunin Courset /T 450 20\b	T _A = 25 °C	1	9.5		
Continuous Drain Current (T _J = 150 °C) ^b	T _A = 70 °C	I _D	7.5		
Pulsed Drain Current		I _{DM}	40	A	
Continuous Source Current (Diode Conduction) ^b		I _S	2.2		
Martin and Branch State of the	T _A = 25 °C	P _D	2.5	w	
Maximum Power Dissipation ^b	T _A = 70 °C	' D	1.6	VV	
Operating Junction and Storage Temperature Ran	nge	T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS ^a					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^b	R _{thJA}	43	50	°C/W	
Maximum Junction-to-Foot (Drain)	R _{thJF}	19	25		

Notes:

a. t ≤ 10 s.

b. Surface Mounted on 1" x 1" FR4 board.

Document Number: 72967 S09-0392-Rev. C, 09-Mar-09

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Datasheet of SI4354DY-T1-E3 - MOSFET N-CH 30V 9.5A 8-SOIC

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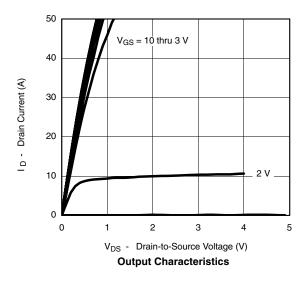
SPECIFICATIONS $T_J = 25$ °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.7		1.6	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	— uA		
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 9.5 \text{ A}$		0.0135	0.0165			
		$V_{GS} = 4.5 \text{ V}, I_D = 9.0 \text{ A}$		0.0154	0.0185	Ω		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 9.5 \text{ A}$		40		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 2.2 A, V _{GS} = 0 V		0.75	1.1	V		
Dynamic ^b								
Total Gate Charge	Q_g			7	10.5			
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 9.5 \text{ A}$		1.85		nC		
Gate-Drain Charge	Q_{gd}			1.20		1		
Gate Resistance	R_g		0.45	0.9	1.35	Ω		
Turn-On Delay Time	t _{d(on)}			8	13			
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω $I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		10	15			
Turn-Off Delay Time	t _{d(off)}			28	45	ns		
Fall Time	t _f			9	15			
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 2.2 \text{ A}, dI/dt = 100 \text{ A/}\mu\text{s}$		35	55			

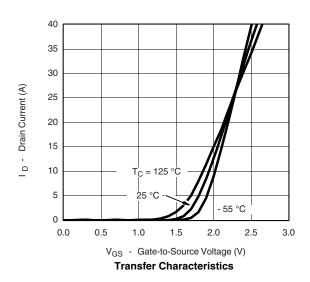
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





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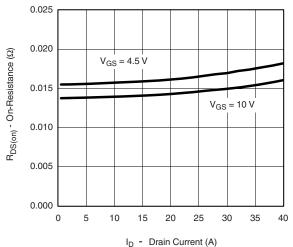




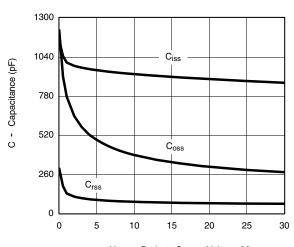
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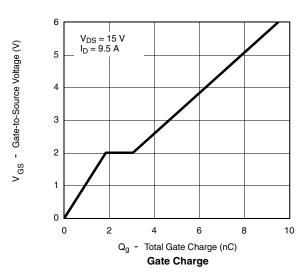


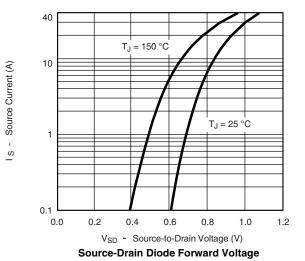
On-Resistance vs. Drain Current



V_{DS} - Drain-to-Source Voltage (V)

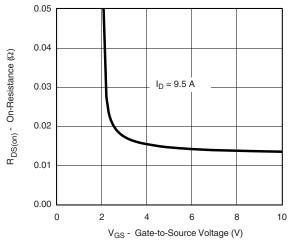






1.6 $V_{GS} = 10 V$ $I_D = 9.5 A$ 1.4 R_{DS(on)} - On-Resistance (Normalized) 1.2 1.0 0.8 0.6 - 25 0 25 100 125 150 - 50 50 75 T_J - Junction Temperature (°C)

On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage

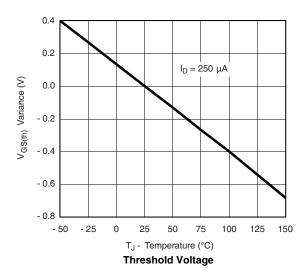
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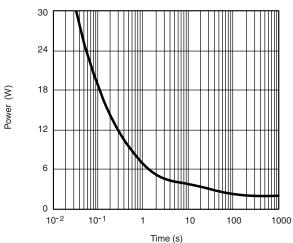
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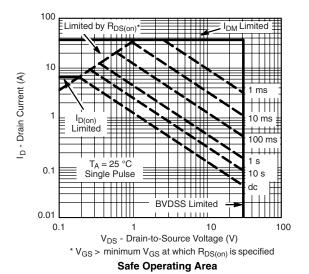
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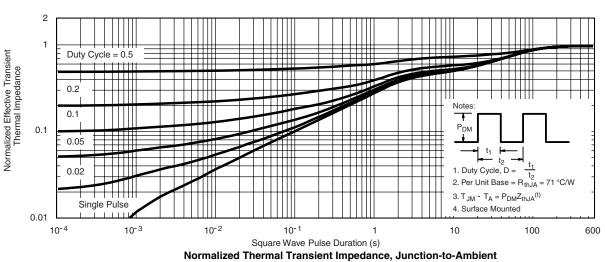






Single Pulse Power, Junction-to-Ambient





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Datasheet of SI4354DY-T1-E3 - MOSFET N-CH 30V 9.5A 8-SOIC

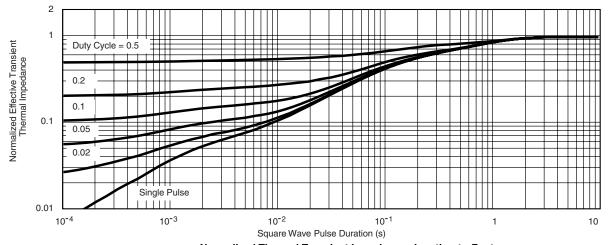
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72967.

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Revision: 13-Jun-16 1 Document Number: 91000